

## Final Exam

**Allowed:** Time – up to 3 hours, formula sheet (given) and calculator

Answer **all** questions from **Section A**, and **two** out of three questions from **Section B**. Both sections are worth equal marks.

### Section A

A1. Consider two equally intense co-propagating red laser beams in free space, with angular frequencies of  $\omega_1$  and  $\omega_2$ , respectively, where  $|\omega_1 - \omega_2| < 2\pi \times 1 \text{ GHz}$ . Calculate the form of the irradiance (also called the intensity) that would be detected by a photodiode which detects frequencies from DC up to 1 GHz.

A2. Explain, using a few sentences, the information conveyed by equation 2.8 on your formula sheet, carefully explaining what each term represents.

A3. Determine expressions for the phase speed, and skin depth [where the intensity has dropped by a factor of  $1/e$ ], of light once it has penetrated a metal surface with high conductivity.

A4. Calculate the linewidth,  $\Delta\nu$  in MHz, of the transition of  $^{20}\text{Ne}$  in a HeNe laser operating on the 632.8 nm transition, assuming the gas temperature is 400 K.

A5 For a typical laser transition with inhomogeneous broadening, determine an expression for the peak cross-section of the transition,  $\sigma_0 \equiv \sigma(\nu_0)$ , in terms of its linewidth  $\Delta\nu$  and the spontaneous decay rate of the transition,  $A_{21}$ . The erbium fiber laser at an output wavelength of 1550 nm, and  $n = 1.46$ , is a three-level laser system, with almost all decays from the upper laser state falling directly to the lower laser state, with a lifetime of 10 ms. The linewidth of the transition at room temperature is 5 THz. What is the peak cross-section of this transition under these circumstances,  $\sigma_0$ ? [to account for the refractive index, replace  $c$  by  $c/n$ ]

### Section B

B1.a) Apply the standard electromagnetic boundary conditions at a vacuum-conducting interface (with the conductivity of the material being  $\sigma$ , assumed non-magnetic) to show that at normal incidence the *reflection coefficient*,  $r$ , is given by:

$$\tilde{r} = \frac{1 - \frac{c\tilde{k}_T}{\omega}}{1 + \frac{c\tilde{k}_T}{\omega}},$$

where  $\tilde{k}_T$  is the transmitted complex wavevector in the conducting material.

b) Given this, for a very good conductor (with  $\tilde{k} \approx \sqrt{\frac{\mu_0 \sigma \omega}{2}}(1+i)$ ) use the binomial approximation to

show that the dependence of the *reflectivity*,  $R$ , on angular frequency is given by  $R \approx 1 - 2\sqrt{\frac{2\omega\epsilon_0}{\sigma}}$ .

Sketch the general form of this function against incident wavelength,  $\lambda$ .

B2. Consider a unidirectional ring laser where light travels from mirror 1 (99% reflective) to mirror 2 (99% reflective), through a gain medium, and towards the output coupler (95% reflective, 4% transmission) before being either transmitted out of the laser or reflected back to mirror 1. The gain medium is a 10 cm long Nd:YAG crystal with a saturation irradiance of 2300 W/cm<sup>2</sup> and the crystal is pumped at a rate that results in a small-signal gain coefficient of 0.05 cm<sup>-1</sup>. Assuming steady state operation:

- Make a sketch of the ring laser, and find the threshold gain coefficient of this cavity.
- Find the irradiance of the laser field that exits from the output coupler.
- What is the irradiance at each end of the gain medium inside the cavity? What are the corresponding values of the gain coefficient,  $\gamma$ , and how do these compare with the threshold gain coefficient? What is the name given to this phenomenon, where the gain coefficient reduces from its small-signal value?

B3. a) Explain, with the aid of one or more diagrams, the physical principle behind the *light emitting diode*. In three or four sentences, explain the information given in the diagram below:

{Figure 16.1-7 from Saleh and Teich, 2<sup>nd</sup> ed.}

b) Explain, with the help of one or more equations, the physical principle behind *non-linear optics*. Show mathematically how the two phenomena known as sum frequency mixing, and difference frequency mixing, arise. What requirement is placed on a crystal to allow such phenomena to occur?